

TITLE OF THE INVENTION:

Please amend the title of the invention as follows:

DISPLAY DEVICE WITH DIVIDED DISPLAY REGIONS

IN THE SPECIFICATION:

Page 15, please amend paragraph [0050] as follows:

The gate signal line GL is formed on the surface of the insulation film GI such that the gate signal line GL extends in the x direction in the drawing. This gate signal line GL is ~~formed~~formed such that a portion thereof is extended into the pixel region and is astride the semiconductor layer AS, thus forming a gate electrode GT of the thin film transistor TFT. Further, a storage line SL is formed simultaneously with the formation of the gate signal line GL. The storage line SL is arranged to be substantially parallel to the gate signal line GL and an extension portion having a relatively large area is defined between the storage line SL and the gate signal line GL. This extension portion of the storage line SL is configured to form one of the electrodes of the capacitive element Cstg.

Page 21, please amend paragraph [0066] as follows:

Then, the conductive layer CL, which is made of an ITO (Indium-Tin-Oxide) film, is formed on an upper surface of the ~~the~~third insulation film PSV. The conductive layer CL is formed simultaneously at the time of forming the pixel electrodes PX in the liquid crystal display portion AR.